

5 BIT PROGRAMMABLE SYNCHRONOUS BUCK PLUS TRIPPLE LDO CONTROLLER

PRELIMINARY DATASHEET

FEATURES

- Designed to meet VRM 9.0 specification for next generation micrprocessors
- On board 5 bit DAC programs the output voltage from 1.075V to 1.850V in 25mV steps
- Linear regulator controller on board for 1.8V
- Provides Single Chip Solution for Vcore, GTL+,AGP Bus, and 1.8V
- Automatic Voltage Selection for AGP slot Vddq supply
- Linear regulator controller on board for 1.5V GTL+ supply
- Loss less Short Circuit Protection for all outputs
- Synchronous operation allows maximum efficiency
- Patented architecture allows fixed frequency operation as well as 100% duty cycle during dvnamic load
- Minimum part count
- Soft Start
- High current totem pole driver for direct driving of the external Power MOSFET
- **■** Power Good function Monitors all Outputs
- OVP Circuitry Protects the Switcher Output and generates a Fault output

APPLICATIONS

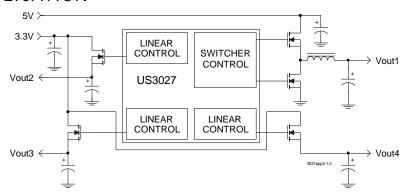
- Total Power Soloution for Next Generation Intel Processor application
- AMD K7 Low Cost Solution

DESCRIPTION

The US3027 controller IC is specifically designed to meet VRM 9.0 specification for next generation microprocessor applications requiring multiple on board regulators. The US3027 provides a single chip controller IC for the Vcore, 3LDO controllers, one with the automatic select pin that connects to the TYPE DETECT pin of the AGP slot for the AGP Vddg supply, one for GTL+ and the other for the 1.8V chip set regulator as required for the next generation PC applications. The US3027 is designed to use either Bipolar transistors for Vout3(1.5V) and Vout4(1.8V) or if Vaux pin is connected to 12V, then MOSFETs can also be used as external pass elements. No external resistor divider is necessary for any of the regulators. The switching regulator feature a patented topology that in combination with a few external components as shown in the typical application circuit, will provide well in excess of 20A of output current for an on-board DC/DC converter while automatically providing the right output voltage via the 5 bit internal DAC . The US3027 also features, loss less current sensing for both switcher by using the Rds-on of the high side Power MOSFET as the sensing resistor, an output under voltage shutdown that detects short circuit condition for the linear outputs and latches the system off, and a Power Good window comparator that switches its open collector output low when any one of the outputs is out-

side of a pre programmed window.

TYPICAL APPLICATION



PACKAGE ORDER INFORMATION

Ta (°C)	Device	Package
0 TO 70	US3027CW	28 pin Plastic SOIC WB

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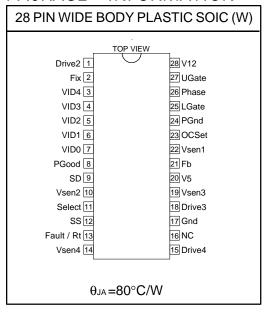
US3027

ABSOLUTE MAXIMUM RATINGS

Storage Temperature Range -65 TO 150°C

Operating Junction Temperature Range 0 TO 125°C

PACKAGE INFORMATION



ELECTRICAL SPECIFICATIONS

Unless otherwise specified ,these specifications apply over ,V12 = 12V, V5 = 5V and Ta=0 to 70° C. Typical values refer to Ta =25°C. Low duty cycle pulse testing are used which keeps junction and case temperatures equal to the

am	bient	temp	erature.

PARAMETER	SYM	M TEST CONDITION		TYP	MAX	UNITS	
Supply UVLO Section							
UVLO Threshold-12V		Supply ramping up		10		V	
UVLO Hysterises-12V				0.6		V	
UVLO Threshold-5V		Supply ramping up		4.4		V	
UVLO Hysterises-5V			0.3		V		
Supply Current							
Operating Supply Current							
		V12		6		mA	
		V5		30			

Switching Controllers; Vcore (Vsen 1) and AGP (Vsen 2)

112 00000011 (10010 0111),					
DAC output voltage (note 1)		0.99Vs	Vs	1.01Vs	V
DAC Output Line Regulation			0.1		%
DAC Output Temp Variation			0.5		%
VID Input LO				0.8	V
VID Input HI		2			V
VID input internal pull-up					
resistor to V5			27		kΩ
Vsen2 Voltage	Select<0.8V		1.5		V
	Select>2V		3.3		V

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Error Comparator Section 2 uA Input Disas current 2 uA Input Offset Voltage -2 +2 mV Delay to Output Vdiff=10mV 100 nS Current Limit Section 200 uA C.S Threshold Set Current 200 uA C.S Comp Offset Voltage -5 +5 mV Hiccup Duty Cycle Css=0.1 uF 10 % Output Drivers Section Rise Time CL=3000pF 70 nS
Input bias current
Input Offset Voltage
Delay to Output Vdiff=10mV 100 nS Current Limit Section 200 uA C.S Threshold Set Current 200 uA C.S Comp Offset Voltage -5 +5 mV Hiccup Duty Cycle Css=0.1 uF 10 % Output Drivers Section Rise Time CL=3000pF 70 nS
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C.S Comp Offset Voltage -5 +5 mV Hiccup Duty Cycle Css=0.1 uF 10 % Output Drivers Section Rise Time CL=3000pF 70 nS
Hiccup Duty Cycle Css=0.1 uF 10 % Output Drivers Section CL=3000pF 70 nS
Output Drivers Section CL=3000pF 70 nS
Rise Time CL=3000pF 70 nS
Fall Time CL=3000pF 70 nS
Dead band Time Between
High side and Synch Drive
(Vcore Switcher Only) CL=3000pF 200 nS
Oscillator Section (internal)
Osc Frequency Rt=Open 217 Khz
1.8V Regulator (Vsen 4)
Vsense Voltage Vo4 Ta=25, Drive4 = Vsen4 1.800 V
Vsense Voltage 1.800 V
Input bias current 2 uA
Output Drive Current Vaux-Vdrive>0.6V 50 mA
Output Drive Current Vaux-vurive>0.0V 30 IIIA
1.5V Regulator (Vsen 3)
Vsense Voltage Vo3 Ta=25, Drive3 = Vsen3 1.500 V
Vsense Voltage 1.500 V
Input bias current 2 uA
Output Drive Current Vaux-Vdrive>0.6V 50 mA
Power Good Section
Vsen1 UV lower trip point Vsen1 ramping down 0.90Vs V
Vsen1 UV upper trip point Vsen1 ramping up 0.92Vs V
Vsen1 UV Hysterises .02Vs V
Vsen1 HV upper trip point Vsen1 ramping up 1.10Vs V
Vsen1 HV lower trip point Vsen1 ramping down 1.08Vs V
Vsen1 HV Hysterises .02Vs V
Vsen2 trip point Select<0.8V 1.100 V
Select>2V 2.560 V
Vsen4 trip point Fix=GND 0.920 V
Fix=Open 1.320 V
Vsen3 trip point Fix=GND 0.920 V
Fix=Open 1.140 V
Power Good Output LO RL=3mA 0.4 V
Power Good Output HI RL=5K pull up to 5V 4.8 V
Fault (Overvoltage) Section
Core O.V. upper trip point Vsen1 ramping up 1.17Vs V
Core O.V. lower trip point Vsen1 ramping down 1.15Vs V
FAULT Output HI Io=3mA 10 V
Soft Start Section
Soft Start Current OCset=0V , Phase=5V 20 uA

Note 1: Vs refers to the set point voltage given in Table 1.

D4	D3	D2	D1	D0	Vs
1	1	1	1	1	1.075
1	1	1	1	0	1.100
1	1	1	0	1	1.125
1	1	1	0	0	1.150
1	1	0	1	1	1.175
1	1	0	1	0	1.200
1	1	0	0	1	1.225
1	1	0	0	0	1.250
1	0	1	1	1	1.275
1	0	1	1	0	1.300
1	0	1	0	1	1.325
1	0	1	0	0	1.350
1	0	0	1	1	1.375
1	0	0	1	0	1.400
1	0	0	0	1	1.425
1	0	0	0	0	1.450

D4	D3	D2	D1	D0	Vs
0	1	1	1	1	1.475
0	1	1	1	0	1.500
0	1	1	0	1	1.525
0	1	1	0	0	1.550
0	1	0	1	1	1.575
0	1	0	1	0	1.600
0	1	0	0	1	1.625
0	1	0	0	0	1.650
0	0	1	1	1	1.675
0	0	1	1	0	1.700
0	0	1	0	1	1.725
0	0	1	0	0	1.750
0	0	0	1	1	1.775
0	0	0	1	0	1.800
0	0	0	0	1	1.825
0	0	0	0	0	1.850

Table 1 - Set point voltage vs. VID codes

PIN DESCRIPTIONS

PIN#	PIN SYMBOL	Pin Description
7	VID0	LSB input to the DAC that programs the output voltage. This pin is TTL compatible that
		realizes a logic "1" as either HI or Open. When left open, his pin is pulled up internally by a $27k\Omega$ resistor to 5V supply.
6	VID1	Input to the DAC that programs the output voltage. This pin is TTL compatible that real-
		izes a logic "1" as either HI or Open. When left open, his pin is pulled up internally by a $27k\Omega$ resistor to 5V supply.
5	VID2	Input to the DAC that programs the output voltage. This pin is TTL compatible that real-
		izes a logic "1" as either HI or Open. When left open, his pin is pulled up internally by a
		27kΩ resistor to 5V supply.
4	VID3	MSB input to the DAC that programs the output voltage. This pin is TTL compatible that
		realizes a logic "1" as either HI or Open. When left open, his pin is pulled up internally by
		a 27kΩ resistor to 5V supply.
3	VID4	This pin selects a range of output voltages for the DAC. When in the LOW state the range
		is 1.3V to 2.05V and when it switches to HI state the range is 2.0V to 3.5V. This pin is
		TTL compatible that realizes a logic "1" as either HI or Open. When left open, his pin is
		pulled up internally by a 27kΩ resistor to 5V supply.
8	PGOOD	This pin is an open collector output that switches LO when any of the outputs are outside
		of the specified under voltage trip point. It also switches low when Vsen1 pin is more than
		10% above the DAC voltage setting.
21	FB	This pin provides the feedback for the synchronous switching regulator. Typically this pin
		can be connected directly to the output of the switching regulator. However, a resistor
		divider is recommended to be connected from this pin to vout1 and GND to adjust the
		output voltage for any drop in the output voltage that is caused by the trace resistance.
		The value of the resistor connected from Vout1 to FB1 must be less than 1000Ω .
1	Drive2	This pin controls the gate of an external MOSFET for the AGP linear regulator.
9	SD	This pin provides shutdown for all the regulatos. A TTL compatible, logic level high applied
		to this pin disables all the outputs and discharges the soft start capacitor. The SD signal
		turns off the synchronous allowing body diode to conduct and discharge the output cap.

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PIN#	PIN SYMBOL	Pin Description
22	Vsen1	This pin is internally connected to the undervoltage and overvoltage comparators sensing
		the Vcore status. It must be connected directly to the Vcore supply.
10	Vsen2	This pin provides the feedback for the AGP linear regulator. The Select pin when con-
		nected to the "Type Detect" pin of the AGP slot automatically selects the right voltage for
		the AGP Vddq.
15	Drive4	This pin controls the gate of an external MOSFET for the 1.8V chip set linear regulator.
23	OCSET	This pin is connected to the Drain of the power MOSFET of the Core supply and it
		provides the positive sensing for the internal current sensing circuitry. An external resis-
		tor programs the C.S threshold depending on the Rds of the power MOSFET. An external
		capacitor is placed in parallel with the programming resistor to provide high frequency
		noise filtering.
26	PHASE	This pin is connected to the Source of the power MOSFET for the Core supply and it
		provides the negative sensing for the internal current sensing circuitry.
12	SS	This pin provides the soft start for all the regulators. An internal current source charges
		an external capacitor that is connected from this pin to GND which ramps up the outputs
		of the regulators, preventing the outputs from overshooting as well as limiting the input
		current. The second function of the Soft Start cap is to provide long off time (HICCUP) for
		the synchronous MOSFET during current limiting.
13	FAULT/Rt	This pin has dual function. It acts as an output of the OVP circuitry or it can be used to
		program the frequency using an external resistor. When used as a fault detector, if any
		of the switcher outputs exceed the OVP trip point, the FAULT pin switches to 12V and
		the soft start cap is discharged. If the FAULT pin is to be connected to any external
40	Debugo	circuitry, it needs to be buffered.
18 19	Drive3 Vsen3	This pin controls the gate of an external transistor for the 1.5V GTL+ linear regulator. This pin provides the feedback for the linear regulator that its output drive is Drive3.
16	NC	This pin is NO connect.
10	NO	This pirts two connect.
14	Vsen4	This pin provides the feedback for the linear regulator that its output drive is Drive4.
17	GND	This pin serves as the ground pin and must be connected directly to the ground plane.
24	PGND	This pin serves as the Power ground pin and must be connected directly to the GND
		plane close to the source of the synchronous MOSFET. A high frequency capacitor
		(typically 1 uF) must be connected from V12 pin to this pin for noise free operation.
25	LGATE	Output driver for the synchronous power MOSFET for the Core supply.
27	UGATE	Output driver for the high side power MOSFET for the Core supply.
28	V12	This pin is connected to the 12 V supply and serves as the power Vcc pin for the output
		drivers. A high frequency capacitor (typically 1 uF) must be placed close to this pin and
		PGND pin and be connected directly from this pin to the GND plane for the noise free
	\	operation.
20	V5	5V supply voltage. A high frequency capacitor (0.1 to 1 uF) must be placed close to this
	0.1.4	pin and connected from this pin to the GND plane for noise free operation.
11	Select	This pin provides automatic voltage selection for the AGP switching regulator. When it is
	FIV	pulled LO, the voltage is 1.5V and when left open or pulled to HI, the voltage is 3.3V.
2	FIX	Leaving this pin open provides fixed output voltages of the 1.5V and 1.8V for the #3 and #4
		linear regulators. When this pin is grounded the reference to the linear regulators are set
		to 1.26V and therefore the output of the regulators can be programmed to any voltages
		above the 1.26V using; Vout=1.26*(1+Rtop/Rbot)
		Where:
		Rtop=Top resistor connected from the output to the Vsense pin
		Rbot=Bottom resistor connected from the Vsense pin to ground.

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BLOCK DIAGRAM

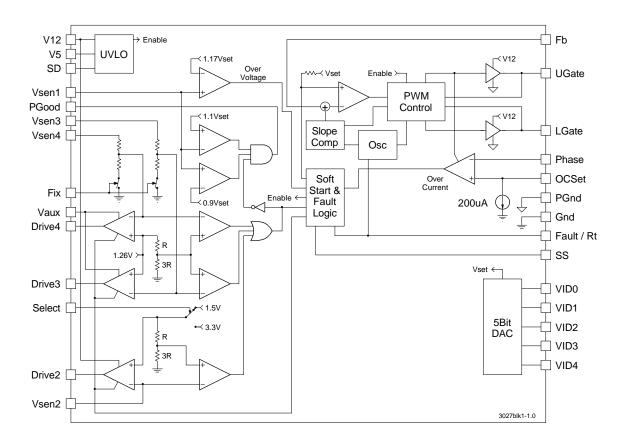


Figure 1 - Simplified block diagram of the US3027.

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TYPICAL APPLICATION

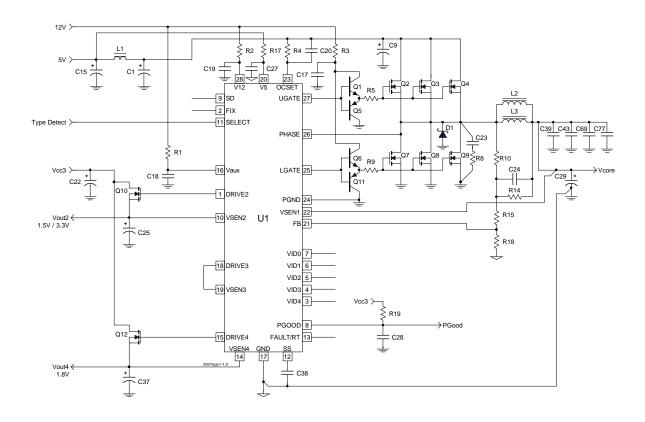


Figure 2 - Typical application of US3027 for the AMD Slot A socket

US3027

US3007 Application Parts List Dual Layout with HIP6019

Ref Desig	Description	Qty	Part#	Manuf
Q1,6	Transistor	2	2SD882, TO226 package	Fair Child
Q2,3,4	MOSFET	3	IRF3706S, TO263 package	IR
Q5,11	Transistor	2	2SB772, TO226 package	Fair Child
Q7,8,9	MOSFET	3	IRL2203NS, TO263 package	IR
Q10	MOSFET	1	IRLR3103S, TO252 package	IR
Q12	MOSFET	1	IRLR024, TO252 package	IR
D1	Diode	1	MBR1535CT, TO220 package	IR
L1	Inductor	1	L=1uH, 5052B core with 5 turns of	Micro Metal
			triple 0.8mm wire	
L2,3	Inductor	2	L=1.8uH, 6018 core with 6 turns of	Micro Metal
			triple 0.8mm wire	
C1	Capacitor, Ceramic	8	1uF, 0603	
C9	Capacitor, Electrolytic	6	10MV1500GX, 1500uF,10V	Sanyo
C15	Capacitor, Electrolytic	1	10MV1500GX, 1500uF,10V	Sanyo
C16	Capacitor, Ceramic	1	1uF, 0603	
C17,18,19	Capacitor, Ceramic	4	1uF, 0805	
,21 C20				
	Capacitor, Ceramic	1	220pF, 0603	
C22,26	Capacitor, Electrolytic	2	6MV1000GX, 1000uF,6.3V	Sanyo
C23	Capacitor, Ceramic	1	1000pF, 0805	
C24,27	Capacitor, Ceramic	2	1uF, 0603	
C25,37	Capacitor, Electrolytic	2	6MV1500GX, 1500uF,6.3V	Sanyo
C28,38	Capacitor, Ceramic	2	0.1uF, 0603	
C29	Capacitor, Electrolytic	8	6MV2200GX, 2200uF,6.3V	Sanyo
C39	Capacitor, Ceramic	4	4.7UF, 0805	
C43	Capacitor, Ceramic	26	1uF, 0603	
C69	Capacitor, Ceramic	8	0.01uF, 0603	
C77	Capacitor, Ceramic	8	39pF, 0603	
R1,2,3,7	Resistor	6	10Ω, 5%, 0603	
,16,21				
R4	Resistor	1	2kΩ, 5%, 0603	
R5,9	Resistor	4	1Ω, 5%, 0805	
R8	Resistor	1	4.7Ω, 5%, 0805	
R10,14	Resistor	2	3.3kΩ, 1%, 0603	
R11,20	Resistor	2	0Ω, 0603	
R12	Resistor	1	47kΩ, 5%, 0603	
R15	Resistor	1	2.2kΩ, 1%, 0603	
R17	Resistor	1	1Ω, 0603	
R18	Resistor	1	100kΩ, 1%, 0603	
R19	Resistor	1	10kΩ, 5%, 0603	

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